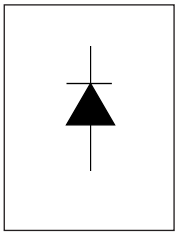
Bulletin I2122 rev. A 07/97

International
IOR Rectifier

*SAFE**IR*** Series
60EPS..

INPUT RECTIFIER DIODE



V_F < 1V @ 30A
I_{FSM} = 950A
V_{RRM} 800 to 1600V

Description/Features

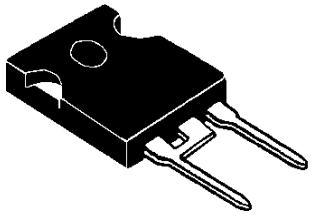
The 60EPS.. rectifier *SAFE**IR*** series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150° C junction temperature.

Typical applications are in input rectification and these products are designed to be used with International Rectifier Switches and Output Rectifiers which are available in identical package outlines.

Major Ratings and Characteristics

Characteristics	60EPS..	Units
$I_{F(AV)}$ Sinusoidal waveform	60	A
V_{RRM}	800 to 1600	V
I_{FSM}	950	A
V_F @30A, T_J = 25°C	1.0	V
T_J	-40 to 150	°C

Package Outline



TO-247AC (Modified)

Voltage Ratings

Part Number	V_{RRM}, maximum peak reverse voltage V	V_{RSM}, maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
60EPS08	800	900	1
60EPS12	1200	1300	
60EPS16	1600	1700	

Absolute Maximum Ratings

	Parameters	60EPS..	Units	Conditions
$I_{F(AV)}$	Max. Average Forward Current	60	A	@ T_C = 118° C, 180° conduction half sine wave
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current	950	A	10ms Sine pulse, rated V_{RRM} applied
		1100		10ms Sine pulse, no voltage reapplied
I^2t	Max. I^2t for fusing	4512	A^2s	10ms Sine pulse, rated V_{RRM} applied
		6300		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$	Max. $I^2\sqrt{t}$ for fusing	63000	$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied

Electrical Specifications

	Parameters	60EPS..	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop	1.07	V	@ 60A, T_J = 25°C	
r_t	Forward slope resistance	3.96	mΩ	T_J = 150°C	
$V_{F(TO)}$	Threshold voltage	0.74	V		
I_{RM}	Max. Reverse Leakage Current	0.1	mA	T_J = 25 °C	V_R = rated V_{RRM}
		1.0		T_J = 150 °C	

Thermal-Mechanical Specifications

	Parameters		60EPS..	Units	Conditions
T_J	Max. Junction Temperature Range		-40 to 150	°C	
T_{stg}	Max. Storage Temperature Range		-40 to 150	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case		0.35	°C/W	DC operation
R_{thJA}	Max. Thermal Resistance Junction to Ambient		40	°C/W	
R_{thCS}	Typical Thermal Resistance, Case to Heatsink		0.2	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		6 (0.21)	g (oz.)	
T	Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)	
		Max.	12 (10)		
	Case Style		TO-247AC		JEDEC (Modified)

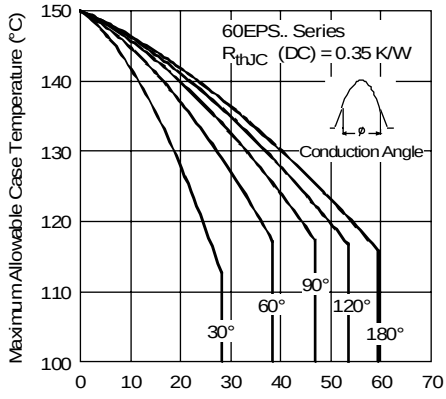


Fig. 1 - Current Rating Characteristics

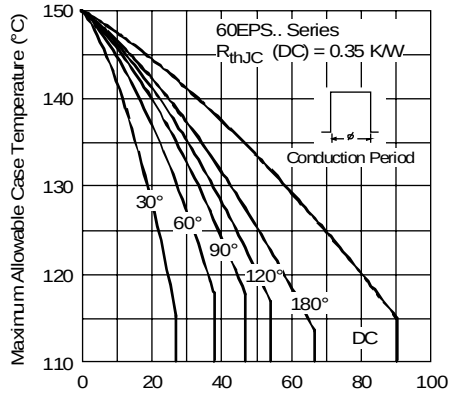


Fig. 2 - Current Rating Characteristics

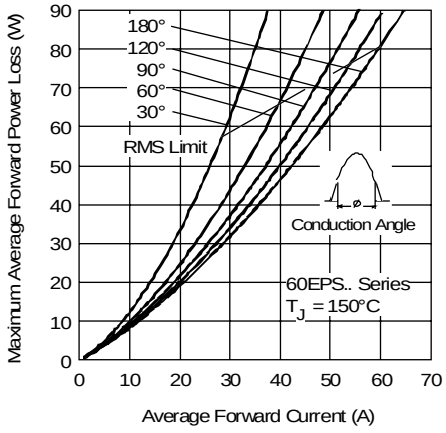


Fig. 3 - Forward Power Loss Characteristics

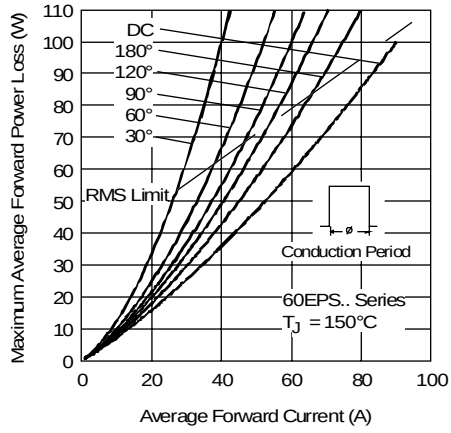


Fig. 4 - Forward Power Loss Characteristics

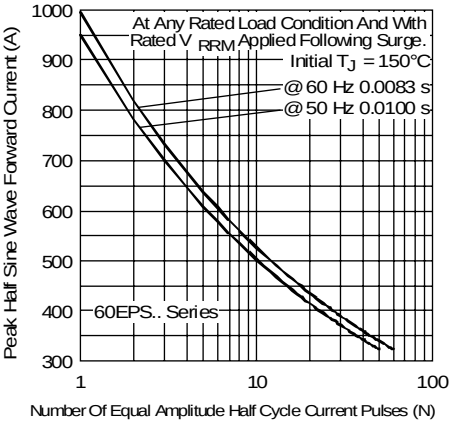


Fig. 5 - Maximum Non-Repetitive Surge Current

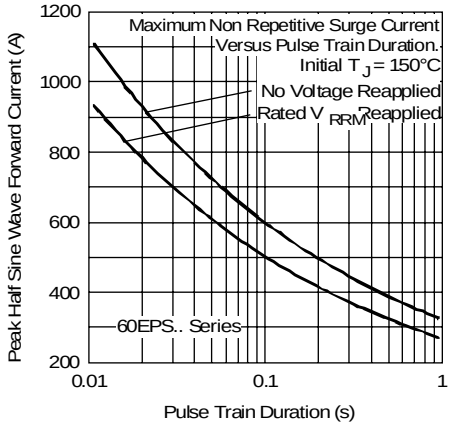


Fig. 6 - Maximum Non-Repetitive Surge Current

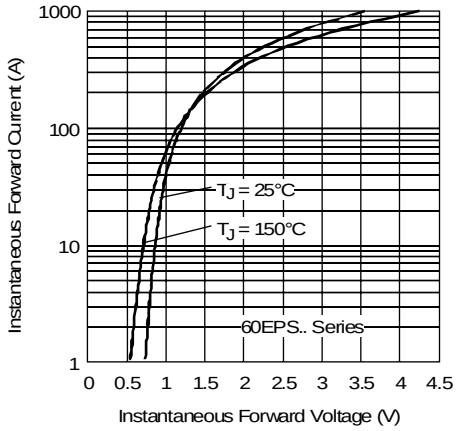


Fig. 7 - Forward Voltage Drop Characteristics

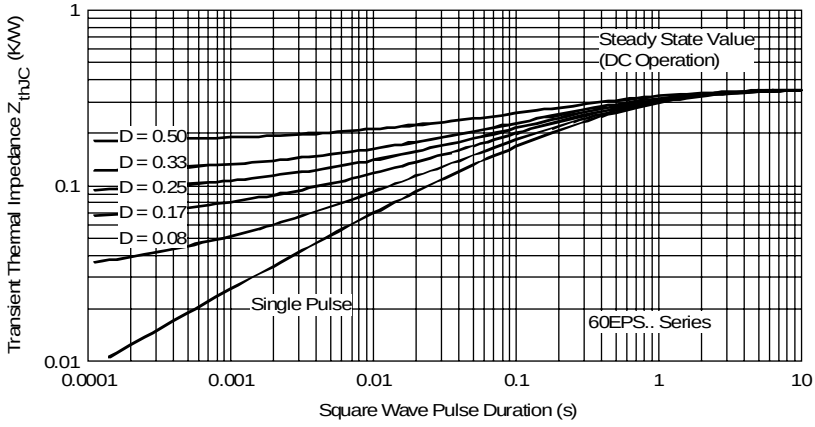
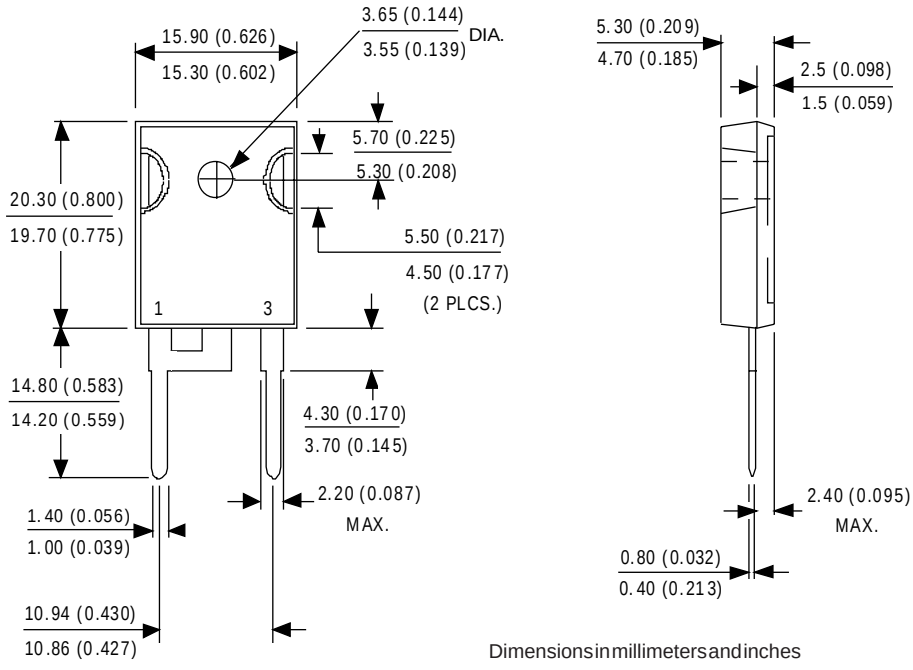


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

Outline Table

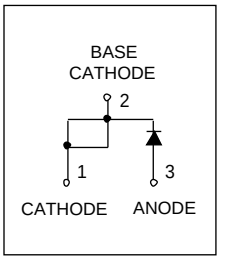


Dimensions in millimeters and inches

Ordering Information Table

Device Code

60	E	P	S	16
1	2	3	4	5



1 - Current Rating

2 - Circuit Configuration:
E = Single Diode

3 - Package:
P = TO-247AC (Modified)

4 - Type of Silicon:
S = Standard Recovery Rectifier

5 - Voltage code: Code x 100 = V_{RRM}

08	=	800V
12	=	1200V
16	=	1600V